2.5 Gbps Transimpedance Amplifier with AGC

**M02015**

**Low-power, high-sensitivity 2.5 Gbps transimpedance amplifier fabricated in sub-micron CMOS**

The M02015 transimpedance amplifier (TIA) with automatic gain control (AGC) is fabricated in sub-micron CMOS for high performance. With typical transimpedance of 9k ohms differential and input-referred noise of 280na, sensitivities of -26 dbm are achievable. With an input overload capability greater than 6ma p-p, the AGC allows more than 32 dB of dynamic range, providing a low-cost solution for longer-reach 2.5 Gbps GPON/ATM/SONET systems, as well as multi-rate 1X/2X Fibre-channel and Gigabit Ethernet transceivers.

For optimum system performance, the M02015 die should be mounted with a silicon or InGaAs PIN photodetector inside a lensed TO-Can or other optical sub-assembly.

**Transimpedance Amplifier (TIA)**

The TIA consists of a high gain single-ended CMOS amplifier with a feedback resistor. The feedback creates a virtual low impedance at the input, and nearly all of the input current passes through the feedback resistor, defining the voltage at the output. Advanced CMOS design techniques are employed to maintain the stability of this stage across all input conditions. An on-chip low dropout linear regulator has been incorporated into the design to give excellent noise rejection up to several MHz. Higher frequency power supply noise is removed by the external 470 pF decoupling capacitor connected to PINK.

**Automatic Gain Control (AGC)**

The M02015 has been designed to operate over the input range of +6 dBm to –26 dBm @ 2.5 Gbps. The AGC operates on signals greater than – 30ua p-p. The AGC pad allows the AGC to be disabled during photodiode alignment by grounding the pad through a low impedance. The AGC control voltage can be monitored during normal operation at this pad by a

**KEY FEATURES**

- Typical -26 dBm sensitivity, > +6 dBm saturation at 2.5 Gbps
- Bandwidth 1.8 Ghz (typical)
- Input-referred noise of 280na (typical)
- Overload of 6ma p-p
- Typical differential transimpedance: 9kΩ
- Maximum jitter of 70 ps p-p
- Differential 100Ω output impedance
- Operates on a single 3.3V supply
- Monitor output
- AGC provides dynamic range of more than 32 dB
high impedance (> 10 MΩ) circuit. A control voltage can drive the AGC pad, locking the gain to a certain value if desired.

**Output Stage**

The signal from the TIA enters a phase splitter followed by a DC-shift stage and a pair of voltage follower outputs. These are designed to drive a differential (100Ω) load. They are stable for driving capacitive loads, such as interstage filters. Each output has its own GND pad, all four GND pads on the chip should be connected for proper operation. Since the M02015 exhibits rapid roll-off (3 pole), simple external filtering is sufficient.

**Monitor O/P**

High impedance output mirrors the average photodiode current for monitoring purposes. The current mirror sinks current to ground. Connecting a 1k ohm resistor to Vcc allows direct voltage measurement.

---

**Recommended Circuit**

![Recommended Circuit Diagram](image)

**Product Highlights**

**Applications**

- ATM/SDH/SONET
- OC-48
- GPON ONU/ONT
- Multi-rate 1X/2X fibre channel and Ethernet

**Ordering Information**

- M02015-A3: waffle pack (WP)
- M02015-QSPBG: quarter wafer

© 2006 Mindspeed Technologies, Inc. All rights reserved. Mindspeed and the Mindspeed logo are trademarks of Mindspeed Technologies. All other trademarks are the property of their respective owners. Although Mindspeed Technologies strives for accuracy in all its publications, this material may contain errors or omissions and is subject to change without notice. This material is provided as is and without any express or implied warranties, including merchantability, fitness for a particular purpose and non-infringement. Mindspeed Technologies shall not be liable for any special, indirect, incidental or consequential damages as a result of its use.